

# 1N5802US/1N5804US/1N5806US Superfast Recovery Diodes Surface Mount (US)

## **POWER DISCRETES**

#### Description

Quick reference data

V<sub>R</sub> 50 -150 V

 $I_{\rm F}$  1N5802US to 1N5806US = 2.5A

 $t_{rr}$  1N5802US to 1N5806US = 25nS

 $I_{R}^{"}$  1N5802US to 1N5806US = 1 $\mu$ A

#### **Features**

- ◆ Very low reverse recovery time
- ◆ Hermetically sealed non-cavity construction
- ◆ Soft, non-snap, off recovery characteristics
- ◆ Very low forward voltage drop

These products are qualified to MIL-PRF-19500/477 and are preferred parts as listed in MIL-HDBK-5961. They can be supplied fully released as JANTX, JANTXV and JANS versions.

#### **Electrical Specifications**

Electrical specifications @  $T_{\Delta}$  = 25°C unless otherwise specified.

	Symbol	1N5802US	1N5804US	1N5806US	Units
Working Reverse Voltage	$V_{_{\mathrm{RWM}}}$	50	100	150	V
Repetitive Reverse Voltage	$V_{RRM}$	50	100	150	V
Average Forward Current (@ 75°C lead length = 0.375')	I <sub>F(AV)</sub>	2.5		А	
Repetitive Surge Current (@ 55°C lead length = 0.375')	I <sub>FRM</sub>	14		А	
Non-Repetitive Surge Current (tp = 8.3mS @ Vr & T <sub>JMAX</sub> )	l <sub>FSM</sub>	35		А	
Storage Temperature Range	T <sub>STG</sub>	-65 to +175		°C	
Average Forward Current Max (pcb mounted: $T_A = 55$ °C) Sine wave Square wave (d = 0.5)	l <sub>F(AV)</sub> l <sub>F(AV)</sub>	1.0 1.1		A	
Pt for fusing (t = 8.3mS) max	l²t	10		A <sup>2</sup> S	
Forward Voltage Drop max @ T <sub>J</sub> = 25°C	V <sub>F</sub>	0.875 @ 1A		V	
Reverse Current max @ $V_{WRM}$ , $T_J = 25^{\circ}C$ @ $V_{WRM}$ , $T_J = 100^{\circ}C$	R   R	1.0 50		μA	
Reverse Recovery Time max (1.0A $I_{\rm F}$ to 1.0A $I_{\rm RM}$ recover to 0.25A $I_{\rm RM(REC)}$ )	trr		25		nS
Junction Capacitance typ  @ V <sub>R</sub> = 5V f = 1MHz	$C_{\mathtt{J}}$	25		pF	
Thermal Resistance to end cap	R <sub><sub>0</sub>JEC</sub>		13		°C/W



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## POWER DISCRETES

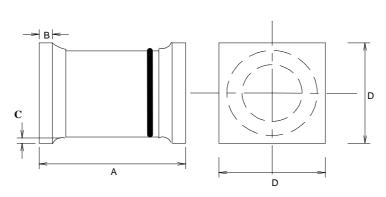
## Ordering Information

Part Number	Description
1N5802US, 1N5804US, 1N5806US	Surface Mount(1)

#### Note:

(1) Available in trays and tape and reel packaging. Please consult factory for quantities.

## Outline Drawing



\*Cathode is denoted by a black band on a white body.

	Dimensions in Inches 1N5802US - 1N5806US				
	MIN	MAX			
А	0.168	0.2			
В	0.019	0.028			
С	0.003	-			
D	0.091	0.103			

## Contact Information

Semtech Corporation Power Discretes Products Division 200 Flynn Road, Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804

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